BLF888D; BLF888DS

UHF power LDMOS transistor Rev. 3 — 1 September 2015

AMMPLEON

Product data sheet

Product profile 1.

1.1 General description

A 600 W LDMOS RF power transistor for broadcast Doherty transmitter applications. The excellent ruggedness of this device makes it ideal for digital and analog transmitter applications.

Table 1. **Application information**

RF performance at $V_{DS} = 50 \text{ V}$ in an ultra wide Doherty application.

Test signal	f	P _{L(AV)}	G _p	η_D	IMD _{shldr}	PAR
	(MHz)	(W)	(dB)	(%)	(dBc)	(dB)
DVB-T (8k OFDM)	470 to 860	115 to 134 🗓	17	40 to 48 🗓	-38 to -44 [2]	8 [3]

- [1] Depending on selected channel.
- [2] Depending on exciter used.
- [3] PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.

1.2 Features and benefits

- High efficiency
- High power gain
- Excellent ruggedness (VSWR ≥ 40 : 1 through all phases)
- Excellent thermal stability
- Integrated ESD protection
- One Doherty design covers the full bandwidth from 470 MHz to 860 MHz
- Internal input matching for ease of use
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Broadcast transmitter applications in the UHF band
- Digital broadcasting

2. Pinning information

Table 2. Pinning

Pin	Description	Simplif	fied outline	Graphic symbol
		Sillipili	neu outime	Grapine symbol
BLF888D (S				
1	drain1 (peak)		1 0	4
2	drain2 (main)		1 2	
3	gate1 (peak)		5	<u> </u>
4	gate2 (main)	;	3 4	5
5	source	[1]		4 7
				├ ─
				2 sym117
				Symiii
BLF888DS (SOT539B)			
1	drain1 (peak)			
2	drain2 (main)		1 2	1
3	gate1 (peak)		5	
4	gate2 (main)	;	3 4	3 — 5
5	source	<u>[1]</u>		4 —
				2
				sym117

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Packag	Package				
	Name	Description	Version			
BLF888D	-	flanged balanced ceramic package; 2 mounting holes; 4 leads	SOT539A			
BLF888DS	-	earless flanged balanced ceramic package; 4 leads	SOT539B			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	drain-source voltage		-	104	V
V_{GS}	gate-source voltage		-0.5	+11	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature	[1]	-	225	°C

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	T_{case} = 75 °C; V_{DS} = 50 V; [1] I_{DS} = 2.7 A (main); I_{DS} = 0 A (peak)	0.27	K/W
		T _{case} = 90 °C; V _{DS} = 50 V; P _L = 115 W; PAR = 8 dB	0.16	K/W

^[1] Measured under DC test conditions, with peak section off.

6. Characteristics

Table 6. DC characteristics

 $T_i = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{(BR)DSS}	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 2.4 \text{ mA}$	104	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	V _{DS} = 10 V; I _D = 240 mA	1.4	1.9	2.4	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 50 V	-	0.061	2.8	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	37	-	Α
I _{GSS}	gate leakage current	V _{GS} = 10 V; V _{DS} = 0 V	-	-	280	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 8.5 A$	-	120	-	mΩ

Table 7. AC characteristics

 $T_i = 25$ °C; per section unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{iss}	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	210	-	pF
Coss	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	70	-	pF
C _{rss}	reverse transfer capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	1.3	-	pF

Table 8. RF characteristics

 V_{DS} = 50 V; I_{Dq} = 1.3 A; T_{case} = 25 °C unless otherwise specified; in a class-AB production test circuit.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Test signal: 2-tone CW						
P _{L(AV)}	average output power	f ₁ = 860 MHz; f ₂ = 860.1 MHz	-	250	-	W
Gp	power gain	f ₁ = 860 MHz; f ₂ = 860.1 MHz	19	21	-	dB
η _D	drain efficiency	f ₁ = 860 MHz; f ₂ = 860.1 MHz	43	45	-	%
IMD3	third-order intermodulation distortion	f ₁ = 860 MHz; f ₂ = 860.1 MHz	-	-32	-29	dBc
Test signal: pulsed CW						
P _{L(3dB)}	output power at 3 dB gain compression	f = 860 MHz; t_p = 100 μs; $δ$ = 10 %	540	580	-	dB

^[2] Measured in an ultra wide Doherty application, using a DVB-T (8k OFDM) signal, PAR (of output signal) at 0.01 % probability on CCDF; PAR of input signal = 9.5 dB at 0.01 % probability on CCDF.

7. Test information

7.1 Ruggedness in Doherty operation

The BLF888D and BLF888DS are capable of withstanding a load mismatch corresponding to VSWR \geq 40 : 1 through all phases under the following conditions: $V_{DS} = 50 \text{ V}$; f = 810 MHz at rated load power.

7.2 Test circuit

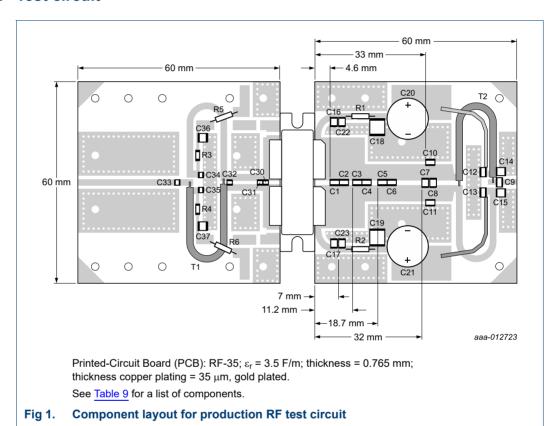


Table 9. List of components For test circuit see Figure 1.

Component	Description	Value	Remarks
C1	multilayer ceramic chip capacitor	12 pF [1]	
C2, C3, C4, C5, C6	multilayer ceramic chip capacitor	8.2 pF [1]	
C7	multilayer ceramic chip capacitor	6.8 pF [2]	
C8	multilayer ceramic chip capacitor	4.7 pF [2]	
C9, C12, C13	multilayer ceramic chip capacitor	100 pF <u>[1]</u>	
C10, C11	multilayer ceramic chip capacitor	10 pF [1]	
C14, C15	multilayer ceramic chip capacitor	4.7 μF, 50 V	
C16, C17	multilayer ceramic chip capacitor	3.6 pF [2]	
C18, C19	multilayer ceramic chip capacitor	4.7 μF, 50 V	
C20, C21	electrolytic capacitor	470 μF, 63 V	

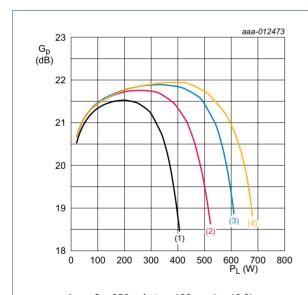
Table 9. List of components ...continued For test circuit see Figure 1.

Component	Description	Value	Remarks
C22, C23	multilayer ceramic chip capacitor	47 pF [2]	
C30	multilayer ceramic chip capacitor	15 pF [3]	
C31	multilayer ceramic chip capacitor	5.6 pF [3]	
C32	multilayer ceramic chip capacitor	2.7 pF [3]	
C33, C34, C35	multilayer ceramic chip capacitor	100 pF [3]	
C36, C37	multilayer ceramic chip capacitor	470 μF, 50 V	
R1, R2	resistor	10 Ω	
R3, R4	resistor	5.6 Ω	SMD 1206
R5, R6	resistor	100 Ω	
R3, R4	resistor	510 Ω	SMD 1206
T1, T2	semi rigid coax	25 Ω, length = 160 mm	Micro-Coax UT-090C-25

- [1] American Technical Ceramics type 180R or capacitor of same quality.
- [2] American Technical Ceramics type 100B or capacitor of same quality.
- [3] American Technical Ceramics type 100A or capacitor of same quality.

7.3 Graphical data

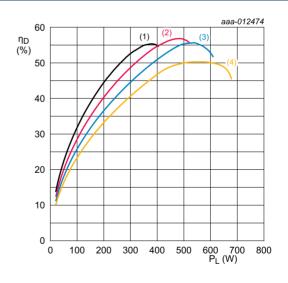
7.3.1 1-Tone CW pulsed



 I_{Dq} = 2 × 650 mA; t_p = 100 μ s; δ = 10 %.

- (1) $V_{DS} = 40 \text{ V}$
- (2) $V_{DS} = 45 \text{ V}$
- (3) $V_{DS} = 50 \text{ V}$
- (4) $V_{DS} = 55 V$

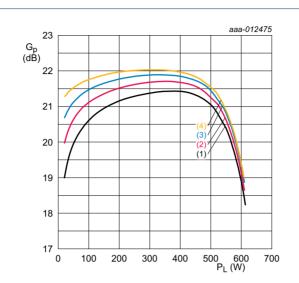
Fig 2. Power gain as a function of output power; typical values



 I_{Dq} = 2 × 650 mA; t_p = 100 μ s; δ = 10 %.

- (1) $V_{DS} = 40 \text{ V}$
- (2) $V_{DS} = 45 V$
- (3) $V_{DS} = 50 \text{ V}$
- (4) $V_{DS} = 55 V$

Fig 3. Drain efficiency as a function of output power; typical values



 V_{DS} = 50 V; t_p = 100 μ s; δ = 10 %.

- (1) $I_{Dq} = 2 \times 250 \text{ mA}$
- (2) $I_{Dq} = 2 \times 450 \text{ mA}$
- (3) $I_{Dq} = 2 \times 650 \text{ mA}$
- (4) $I_{Dq} = 2 \times 850 \text{ mA}$

Fig 4. Power gain as a function of output power; typical values

8. Package outline

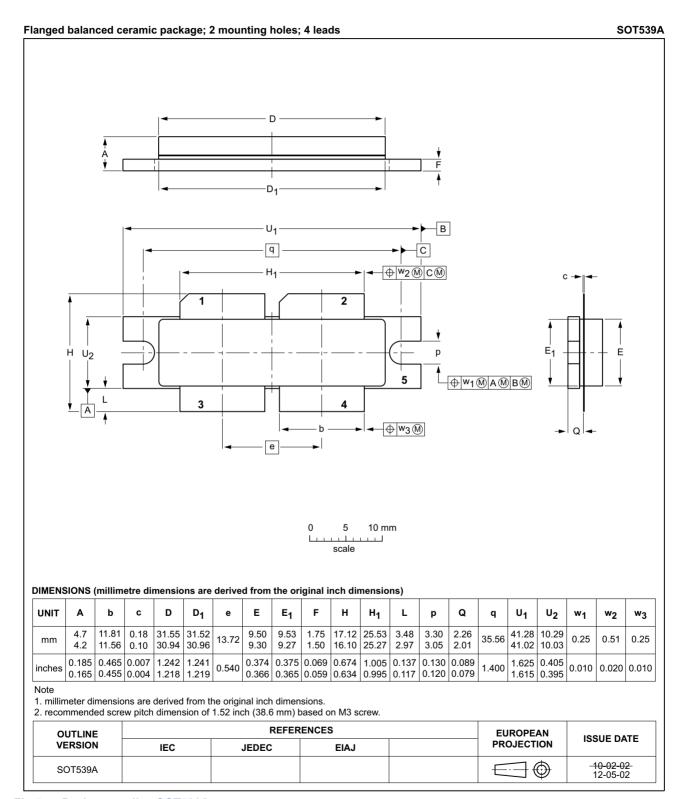


Fig 5. Package outline SOT539A

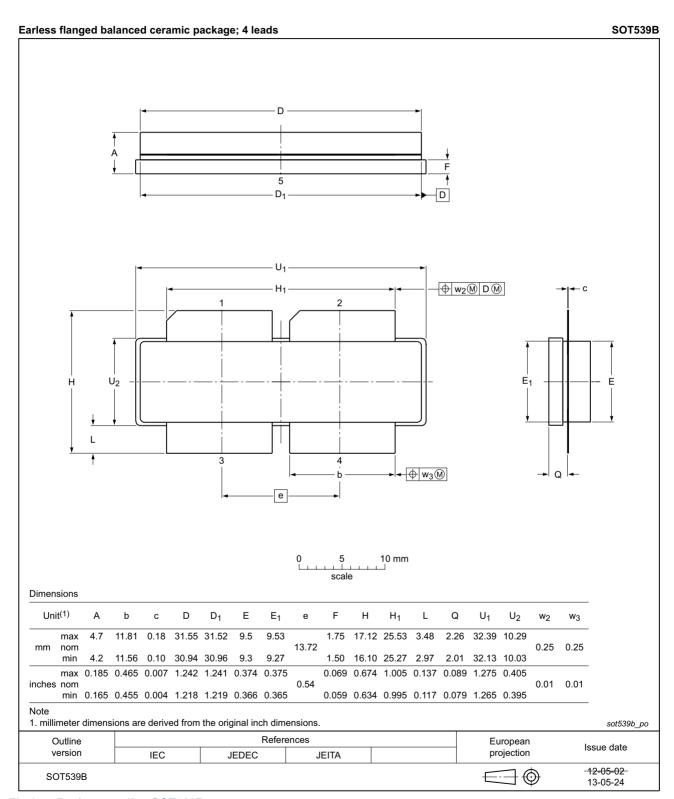


Fig 6. Package outline SOT539B

BLF888D; BLF888DS

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9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

Acronym	Description
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DVB-T	Digital Video Broadcast - Terrestrial
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
OFDM	Orthogonal Frequency Division Multiplexing
PAR	Peak-to-Average Ratio
SMD	Surface Mounted Device
UHF	Ultra High Frequency
VSWR	Voltage Standing-Wave Ratio

11. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes		
BLF888D_BLF888DS#3	20150901	Product data sheet	-	BLF888D_BLF888DS v.2		
Modifications:		 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. 				
	Legal texts have been adapted to the new company name where appropriate.					
BLF888D_BLF888DS v.2	20140627	Product data sheet	-	BLF888D_BLF888DS v.1		
BLF888D_BLF888DS v.1	20140305	Objective data sheet	-	-		

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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